



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Appl. No. : 09/805,273
Applicant : YANG, Wenge
Filed : 3/13/01
Art Unit : 2823
Examiner : Estrada, Michelle
Atty Docket No. : AMD-E365

Confirmation No. 1234

For: HIGHLY CONDUCTIVE SEMICON-
DUCTOR STRUCTURES, METHOD OF
FORMING SAME VIA PLASMA ETCH, AND
ELECTRICAL DEVICES INCORPORATING
HIGHLY CONDUCTIVE SEMICONDUCTOR
STRUCTURES

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RESPONSE TO OFFICE ACTION

Dear Sir:

In response to the Non-Final Office Action mailed September 22nd, 2005,
please consider the following remarks and enter the following amendments.

An amendments to the Title is presented on page 2 of this response.
Amendments to the Claims begin on page 2 of this response. Remarks begin on
page 7 of this response.